

PCN# 20140319001A Add Cu as Alternative Wire Base Metal for Selected Device(s) on QFN, QFP and SOT-23 packages Change Notification / Sample Request

Dear Customer:

The purpose of this version A is to retract and add devices from this change notification. The retraction is for select devices that were inadvertently included and are not affected by this change. We apologize for any inconvenience this may have caused

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (<u>PCN ww admin team@list.ti.com</u>).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659

PCN# 20140319001A Attachment: 1

Products Affected:

According to our records, there are the affected device(s) that you have purchased within the past twenty-four (24) months. Technical details of this Product Change follow on the next page(s).

PCN Number: 20140319001A			A			PCN Date:		05/15/2014		
Title: Add Cu as Alternative Wire Base Metal for Selected Device(s) on QFN, QFP and SOT-23 packages										
Custom	er Contact:	PCN /	Manager		Phone:	+1(214)480-60	37	Dept:	Qual	ity Services
Proposed 1 st Ship Date: 08/15/2014			014					Date provided at sample request		
Change Type:										
	ssembly Site				Design			Wafer Bump Site		
	ssembly Proce	SS			Data Sheet			Wafer Bump Material		
	ssembly Mater	rials			Part number change			Wafer Bump Process		rocess
M	echanical Spe	cifica	tion		Test Site 📃 Wafer Fa			ab Site		
Pa	acking/Shippir	ng/La	beling		Test Process			Wafer Fab Materials		
						Wafer Fa	b Prod	cess		
PCN Details										
Description of Change:										
The purpose of Revision A is to Retract devices (which were inadvertently added and are not affected										

- by this change) and to Add devices under Group 3 in the Product Affected Section.
 - Retracted device with strikethrough and highlighted in yellow
 - Additional device highlighted in yellow

Texas Instruments is pleased to announce the qualification of Cu as an additional bond wire option for devices listed in "Product affected" section below. Devices will remain in current assembly facility and piece part changes as follows.

Group 1 Device: No other piece part change, Only Au to Cu wire

Group 2 Device: Changes Wire Composition and Wire Diameter

	From	То
Wire	0.96 mil Au	0.80 mil Cu

Group 3 Device: Changes Mold Compound, Wire Composition and Wire Diameter

	From	То
Mold Compound	450207, 450228	450413
Wire	0.60, 0.80, 1.0 mil Au	0.80, 1.0 mil Cu

Reason for Change:

Continuity of supply.

- 1) To align with world technology trends and use wiring with enhanced mechanical and electrical properties
- 2) Maximize flexibility within our Assembly/Test production sites.
- 3) Cu is easier to obtain and stock

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

None.

Changes to product identification resulting from this PCN:

None.

Product Affected: Group 1 devices - No other piece part change, Only Au to Cu wire					
TPS65633ARTER TPS65633RTER TPS65633RTET					
Product Affected: Grou			Diameter		
		/91670PHPR			
Product Affected: Grou			ion and Wire Diameter		
74AHC1G125DBVRE4	SN74AHC1G08DBVR	SN74LVC1G32DBVRG4			
74AHC1G125DBVRG4	SN74AHC1G08DBVRE4	SN74LVC1G34DBVR	TS5A4594DBVRG4		
74AHC1G126DBVRE4	SN74AHC1G08DBVRG4	SN74LVC1G34DBVRE4	SN74AHC1G02DBVT		
74AHC1G126DBVRG4	SN74AHC1G125DBVR	SN74LVC1G34DBVRG4	SN74AHC1G86DBV6		
74AHC1GU04DBVRE4	SN74AHC1G126DBVR	SN74LVC1G66DBVR	SN74AHC1G86DBVT		
74AHC1GU04DBVRG4	SN74AHC1G86DBVR	SN74LVC1G66DBVRE4	SN74AHC1GU04DBVT		
74AHCT1G00DBVRE4	SN74AHC1G86DBVRE4	SN74LVC1G66DBVRG4	SN74AHCT1G00DBVT		
74AHCT1G00DBVRG4	SN74AHC1G86DBVRG4	SN74LVC1G79DBVR	SN74AHCT1G04DBVT		
74AHCT1G04DBVRE4 74AHCT1G04DBVRG4	SN74AHC1GU04DBVR	SN74LVC1G79DBVRE4 SN74LVC1G79DBVRG4	SN74AHCT1G125DBVT		
74AHCT1G04DBVRG4	SN74AHCT1G00DBVR		SN74AHCT1G86DBV6		
	SN74AHCT1G04DBVR	SN74LVC1G80DBVR	SN74AHCT1G86DBVT SN74AUC1G04DBVR		
74AHCT1G08DBVRG4 74AHCT1G125DBVRE4	SN74AHCT1G08DBVR SN74AHCT1G125DBVR	SN74LVC1G80DBVRE4 SN74LVC1G80DBVRG4	SN74AUC1G04DBVR SN74AUC1G08DBVR		
74AHCT1G125DBVRE4			SN74AUC1G08DBVR		
74AHCT1G125DBVRG4 74AHCT1G126DBVRE4	SN74AHCT1G126DBVR	SN74LVC1G86DBVR SN74LVC1G86DBVRE4	SN74AUC1G125DBVR SN74AUC1G240DBVR		
74AHCT1G126DBVRG4	SN74AHCT1G32DBVR SN74AHCT1G86DBVR	SN74LVC1G86DBVRE4	SN74AUP1G04DBVT		
74AHCT1G126DBVRG4 74AHCT1G32DBVRE4	SN74AUP1G04DBVR		SN74AUP1G04DBVT SN74AUP1G14DBVR		
74AHCT1G32DBVRE4	SN74AUP1G04DBVRE4	SN74LVC1GU04DBVR TL343IDBVR	SN74AUP1G14DBVR SN74AUP1G32DBVR		
74AHCT1G32DBVRG4 74AHCT1G86DBVRE4	SN74AUP1G04DBVRE4	TL343IDBVR TL343IDBVRE4	SN74AUP1G32DBVR SN74AUP1G34DBVR		
74AHCT1G86DBVRG4	SN74AUP1G04DBVRG4	TL343IDBVRG4	SN74CBT1G384DBVR		
74AUP1G125DBVRE4	SN74AUP1G07DBVRE4	TL431ACDBVR	SN74CBT1G384DBVK		
74AUP1G125DBVRG4	SN74AUP1G07DBVRG4	TL431ACDBVRE4	SN74CBTD1G125DBVR		
74CBT1G125DBVR64	SN74AUP1G125DBVR	TL431ACDBVRG4	SN74CBTD1G125DBVK		
74CBT1G125DBVRC4	SN74CBT1G125DBVR	TL431CDBVR	SN74CBTD1G125DBVT		
74CBTLV1G125DBVRE4	SN74CBTLV1G125DBVR	TL431CDBVRE4	SN74LVC1G02DBVT		
74CBTLV1G125DBVRG4	SN74LVC1G02DBVR	TL431CDBVRG4	SN74LVC1G06DBVT		
74LVC1G126DBVRE4	SN74LVC1G02DBVRE4	TL431IDBVR	SN74LVC1G07DBVT		
74LVC1G126DBVRG4	SN74LVC1G02DBVRG4	TL431IDBVRE4	SN74LVC1G132DBVT		
74LVC1G132DBVRE4	SN74LVC1G06DBVR	TL431IDBVRG4	SN74LVC1G14DBVT		
74LVC1G132DBVRG4	SN74LVC1G06DBVRE4	TLV431AIDBVR	SN74LVC1G240DBVT		
74LVC1G240DBVRE4	SN74LVC1G06DBVRG4	TLV431AIDBVRE4	SN74LVC1G32DBVT		
74LVC1G240DBVRG4	SN74LVC1G07DBVR	TLV431AIDBVRG4	SN74LVC1G34DBVT		
74LVC1GU04DBVRE4	SN74LVC1G07DBVRE4	TLV431CDBVR	SN74LVC1G66DBVT		
74LVC1GU04DBVRG4	SN74LVC1G07DBVRG4	TLV431CDBVRE4	SN74LVC1G79DBVT		
SN003166DBVR	SN74LVC1G126DBVR	TLV431CDBVRG4	SN74LVC1G80DBVT		
SN1003028DBVR	SN74LVC1G132DBVR	TLV431IDBVR	SN74LVC1G86DBVT		
SN74AHC1G02DBVR	SN74LVC1G14DBVR	TLV431IDBVRE4	SN74LVC1GU04DBVT		
SN74AHC1G02DBVRE4	SN74LVC1G14DBVRE4	TLV431IDBVRG4	TL431CDBVT		
SN74AHC1G02DBVRG4	SN74LVC1G14DBVRG4	TS5A3166DBVR	TS5A4595DBVR		
SN74AHC1G04DBVR	SN74LVC1G240DBVR	TS5A3166DBVRE4			
SN74AHC1G04DBVRE4	SN74LVC1G32DBVR	TS5A3166DBVRG4			
SN74AHC1G04DBVRG4	SN74LVC1G32DBVRE4	TS5A4594DBVR			

Qualification Data : Group 1 Devices

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This qualification has been developed for the validation of this change. The qualification data						
validates that the proposed change meets the applicable released technical specifications. Qual Vehicle 1 : TPA2017D2RTJ (MSL 2-260C)						
Qua			JC)			
	Package Constr					
Assembly Site:	TI-Clark	Mold Compour		4208		
.	20-RTJ, QFN	Mount Compour	nd:	4207		
	NiPdAu, Cu	Bond Wi	re:	0.96	Mil Dia.,	Cu
Qualification: 🗌 Plan	Test Results					
				San	nple Size/	Fail
Reliability Test	Conditions			t# 1	Lot# 2	Lot# 3
**High Temp Storage Bake	170C (420 Hrs)			6/0	87/0	87/0
**Autoclave	121C (240 Hrs)			7/0	87/0	87/0
**T/C -65C/150C	-65C/+150C (500 Cy	/C)		7/0	77/0	77/0
X-ray	(top side only)			5/0	5/0	-
Salt Atmosphere	24 Hours			2/0	22/0	22/0
Surface Mount Solderability	8 Hours Steam Age-Pb Free Solder			2/0 ass	22/0	22/0
Manufacturability (Assembly)					Pass	Pass
Moisture Sensitivity	(level 2 @ 260C peak +5/-0C)			2/0	12/0	12/0
	sequence: Level 2-2600		-			
Qu	al Vehicle 2 : TPS25	• •	C)			
	Package Constr					
Assembly Site:	I-Clark Mold Compou			4208		
# Pins-Designator, Family:	16-RTE, QFN Mount Compou		ind: 4207768			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire: 2.0 Mil Dia., C		u		
Qualification: 🗌 Plan	Test Results					
				San	nple Size/	Fail
Reliability Test	Conditions		Lot# 1		Lot# 2	Lot# 3
** Life Test	150C (408 Hrs)		77/0		77/0	77/0
**High Temp Storage Bake	175C (500 Hrs)		78/0		80/0	79/0
**Autoclave	121C (240 Hrs)	```	87/0		87/0	87/0
**Biased HAST	130C/85%RH (96 Hr		77/0		77/0	77/0
**Temperature Cycle	-65C/+150C (500 C)	/C)	77/0		77/0	77/0
Surface Mount Solderability	Pb Free/Solder-			5/0	15/0	-
Manufacturability (Assembly)			Pass		Pass	Pass
Moisture Sensitivity	(level 2 @ 260C peal		1	2/0	12/0	12/0
Notes **- Preconditioning sequence: Level 2-260C.						

Oualification Data : Group 2 Devices

This qualification has been developed for the validation of this change. The qualification data							
validates that the proposed cl	validates that the proposed change meets the applicable released technical specifications.						
Qua	I Vehicle 1 : DRV916	570PHPR (MSL 3-26	0C)				
	Package Construction Details						
Assembly Site:	TAI	Mold Compou	nd: 420	5443			
# Pins-Designator, Family:	48-PHP, HTQFP	Mount Compou	nd: 420	3458			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	ire: 0.80	Mil Dia.,	Cu		
Qualification: Plan	Test Results						
Delie bility Teet	Conditions		Sample Size/Fail				
Reliability Test			Lot# 1	Lot# 2	Lot# 3		
Electrical Characterization	-		Pass	Pass	Pass		
**High Temp Storage Bake	170C (420 Hrs)		77/0	77/0	77/0		
**Autoclave	121C (96 Hrs)		77/0	77/0	77/0		
** Temperature Cycle	-65C/+150C (500 Cyc)		77/0	77/0	77/0		
ESD CDM	+/- 250V; +/- 1500V		3/0	-	-		
ESD HBM	+/- 1000V; +/- 2500V		3/0	-	-		
Manufacturability (Assembly)			Pass	Pass	Pass		
Moisture Sensitivity	(level 3 @ 260C peak +5/-0C)		12/0	-	-		
Notes **- Preconditioning s	equence: Level 3-2600						
Qualification Data : Group 3 Devices							

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validates that the proposed change meets the applicable released technical specifications							
Qual Vehicle 1 : SN74AHC1G126DBVR (MSL 1-260C)							
	Package Construction Details						
Assembly Site:	HNT	HNT Mold Compoun		d: 450413			
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour	nd: 4001	.54			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re: 1.0 N	1.0 Mil Dia., Cu			
Qualification: 🗌 Plan 🛛 Test Results							
Reliability Test	Conditions		Sample Si		/Fail		
Reliability Test			Lot# 1	Lot# 2	Lot# 3		
**High Temp Storage Bake	170C (600 Hrs)		82/0	85/0	84/0		
**Autoclave	121C (192 Hrs)		77/0	77/0	77/0		
** Temperature Cycle	-65C/+150C (500 Cy	-65C/+150C (500 Cyc)		77/0	77/0		
Moisture Sensitivity	(level 1 @ 260C peak +5/-0C)		22/0	22/0	22/0		
Notes **- Preconditioning sequence: Level 1-260C.							

Qual V	ehicle 2 : SN74CBTLV	/1G125DBVR (MSL 1	-26	DC)		
	Package Constr			-		
Assembly Site:	HNT	Mold Compour	nd:	4504	13	
# Pins-Designator, Family:	Pins-Designator, Family: 5-DBV, SOT-23 Mount Compou			4001	54	
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi			1il Dia., C	u
Qualification: Plan	Test Results					-
Reliability Test	Conditions			San	nple Size/	Fail
**High Temp Storage Bake	170C (600 Hrs)				90/0	
**Autoclave	121C (96 Hrs)				77/0	
**T/C -65C/150C	-65C/+150C (500 C)	/c)			77/0	
	sequence: Level 1-2600				,	
	Vehicle 3 : SN74LVC1		260	C)		
•	Package Constr			-		
Assembly Site:	HNT	Mold Compour	nd:	4504	13	
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour	nd:	4001	54	
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re:	0.80	Mil Dia.,	Cu
Qualification: Plan	Test Results					
Reliability Test	Conditions	Conditions			nple Size/Fail	
			Lot# 1 87/0		Lot# 2	Lot# 3
**High Temp Storage Bake	170C (420 Hrs)			•	87/0	89/0
**Autoclave	121C (192 Hrs)	1		7/0	77/0	77/0
**Biased HAST	130C/85%RH (192 H			0/0	80/0	80/0
** Temperature Cycle	-65C/+150C (500 Cyc)			7/0	77/0	77/0
Solderability	Pb Free/Solder			2/0	22/0	22/0
Manufacturability (Assembly				ass	Pass	Pass
Moisture Sensitivity					22/0	
	sequence: Level 1-2600		••			
	Qual Vehicle 4 : TS32		·)			
Accomply City	Package Const		. d .	4504	10	
Assembly Site:	HNT	Mold Compour		4504		
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour				
Lead frame (Finish, Base):	NiPdAu, Cu Bond Wire: 1.0 Mil Dia., Cu				u	
Qualification: 🗌 Plan	Test Results					
Reliability Test	Conditions		Samp		ple Size/Fail	
Rendbinty rest			Lo	t# 1	Lot# 2	Lot# 3
**High Temp Storage Bake	170C (420 Hrs)		79/0		80/0	80/0
**Autoclave	121C (192 Hrs)		77/0		77/0	77/0
** Temperature Cycle	-65C/+150C (500 Cy	/c)	77/0		77/0	77/0
Moisture Sensitivity	(level 1 @ 260C pea		2	2/0	22/0	22/0
Notes **- Preconditioning	sequence: Level 1-2600	2.				

Qual Vehicle 5 : TS5A3166DBVR (MSL 1-260C)					
Package Construction Details					
Assembly Site:	HNT	Mold Compound	d: 450413		
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compound	d: 400154		
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire	e: 0.8 Mil Dia., Cu		
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test	Conditions	Conditions			
**Autoclave	121C (96 Hrs)	121C (96 Hrs)			
** Temperature Cycle	-65C/+150C (500 Cy	-65C/+150C (500 Cyc)			
Notes **- Preconditioning sequence: Level 1-260C.					

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com